

TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

**TC74HC240AP, TC74HC240AF, TC74HC240AFW, TC74HC241AP
TC74HC241AF, TC74HC244AP, TC74HC244AF, TC74HC244AFW**
OCTAL BUS BUFFER

TC74HC240AP/AF/AFW INVERTED, 3 - STATE OUTPUTS
TC74HC241AP/AF NON - INVERTED, 3 - STATE OUTPUTS
TC74HC244AP/AF/AFW NON - INVERTED, 3 - STATE OUTPUTS

The TC74HC240A, 241A and 244A are high speed CMOS OCTAL BUS BUFFERs fabricated with silicon gate C2MOS technology.

They achieve the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

The 74HC240A is an inverting 3 - state buffer having two active - low output enables. The TC74HC241A and TC74HC244A are non - inverting 3 - state buffers that differ only in that the 241A has one active - high and one active - low output enable, and the 244A has two active - low output enables.

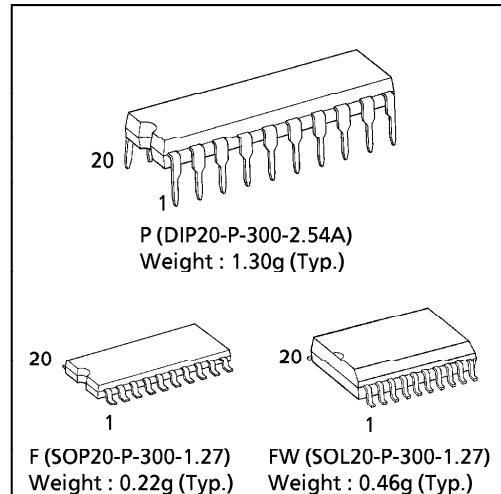
These devices are designed to be used with 3 - state memory address drivers, etc.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

FEATURES :

- High Speed..... $t_{pd} = 10\text{ns}(\text{typ.})$ at $V_{CC} = 5\text{V}$
- Low Power Dissipation..... $I_{CC} = 4\mu\text{A}(\text{Max.})$ at $T_a = 25^\circ\text{C}$
- High Noise Immunity..... $V_{NIH} = V_{NIL} = 28\% V_{CC}$ (Min.)
- Output Drive Capability 15 LSTTL Loads
- Symmetrical Output Impedance... $|I_{OH}| = I_{OL} = 6\text{mA}(\text{Min.})$
- Balanced Propagation Delays..... $t_{PLH} \approx t_{PHL}$
- Wide Operating Voltage Range.... V_{CC} (opr.) = $2\text{V} \sim 6\text{V}$
- Pin and Function Compatible with 74LS 240 / 241 / 244

(Note) The JEDEC SOP (FW) is not available in Japan.

**TRUTH TABLE**

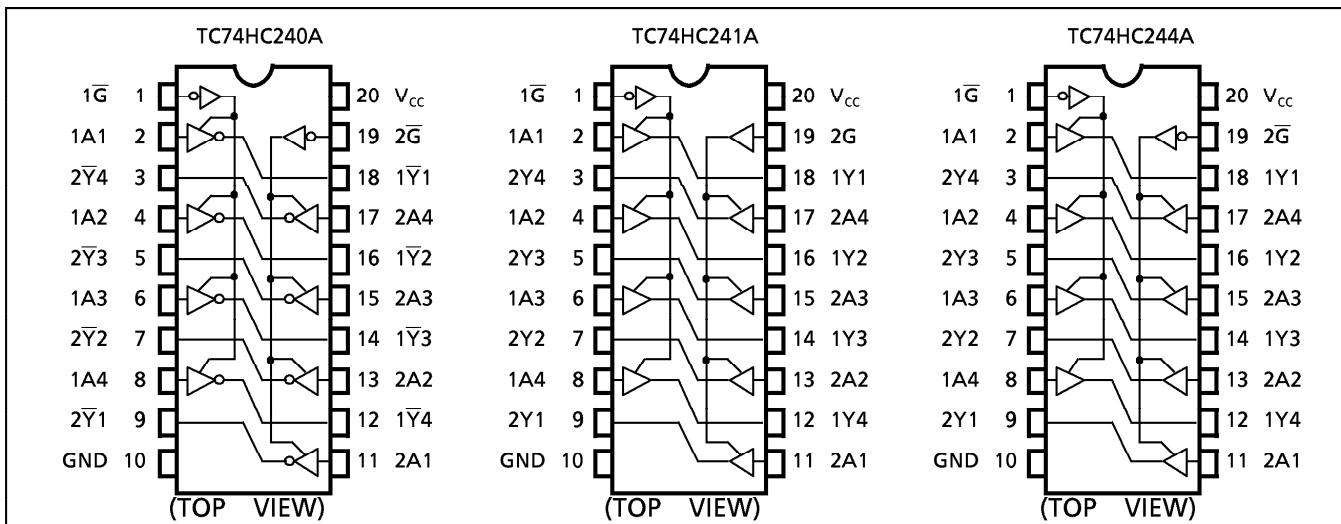
| INPUTS | | | OUTPUTS | |
|-----------|------------|-------|---------|----------------------------|
| \bar{G} | G^Δ | A_n | Y_n | $\bar{Y}_n^{\Delta\Delta}$ |
| L | H | L | L | H |
| L | H | H | H | L |
| H | L | X | Z | Z |

Δ : for TC74HC241A only

$\Delta\Delta$: for TC74HC240A only

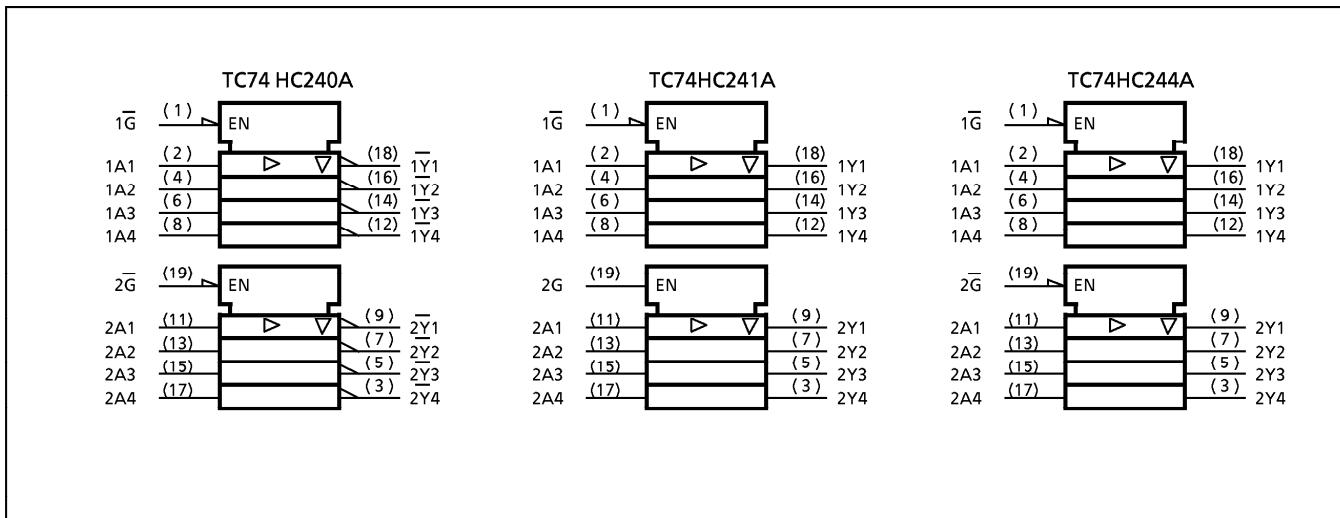
X : Don't Care

Z : High Impedance

PIN ASSIGNMENT

● TOSHIBA is continually working to improve the quality and the reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to observe standards of safety, and to avoid situations in which a malfunction or failure of a TOSHIBA product could cause loss of human life, bodily injury or damage to property. In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent products specifications. Also, please keep in mind the precautions and conditions set forth in the TOSHIBA Semiconductor Reliability Handbook.

IEC LOGIC SYMBOL



961001EBA2'

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- The information contained herein is subject to change without notice.

ABSOLUTE MAXIMUM RATINGS

| PARAMETER | SYMBOL | VALUE | UNIT |
|------------------------------|-----------|------------------------|------|
| Supply Voltage Range | V_{CC} | -0.5~7 | V |
| DC Input Voltage | V_{IN} | -0.5~ V_{CC} +0.5 | V |
| DC Output Voltage | V_{OUT} | -0.5~ V_{CC} +0.5 | V |
| Input Diode Current | I_{IK} | ± 20 | mA |
| Output Diode Current | I_{OK} | ± 20 | mA |
| DC Output Current | I_{OUT} | ± 35 | mA |
| DC V_{CC} / Ground Current | I_{CC} | ± 75 | mA |
| Power Dissipation | P_D | 500 (DIP)* / 180 (SOP) | mW |
| Storage Temperature | T_{Stg} | -65~150 | °C |

*500mW in the range of $T_a = -40^{\circ}\text{C} \sim 65^{\circ}\text{C}$. From $T_a = 65^{\circ}\text{C}$ to 85°C a derating factor of $-10\text{mW}/^{\circ}\text{C}$ shall be applied until 300mW.

RECOMMENDED OPERATING CONDITIONS

| PARAMETER | SYMBOL | VALUE | UNIT |
|--------------------------|------------|---|------|
| Supply Voltage | V_{CC} | 2~6 | V |
| Input Voltage | V_{IN} | 0~ V_{CC} | V |
| Output Voltage | V_{OUT} | 0~ V_{CC} | V |
| Operating Temperature | T_{opr} | -40~85 | °C |
| Input Rise and Fall Time | t_r, t_f | 0~1000 ($V_{CC} = 2.0\text{V}$) 0~500 ($V_{CC} = 4.5\text{V}$) 0~400 ($V_{CC} = 6.0\text{V}$) | ns |

DC ELECTRICAL CHARACTERISTICS

| PARAMETER | SYMBOL | TEST CONDITION | V_{CC} (V) | Ta = 25°C | | | Ta = -40~85°C | | UNIT |
|--------------------------------------|----------|--|--|----------------------|-------------------|-------------------|----------------------|-------------------|-------------------|
| | | | | MIN. | TYP. | MAX. | MIN. | MAX. | |
| High - Level Input Voltage | V_{IH} | | 2.0 4.5 6.0 | 1.50 3.15 4.20 | — — — | — — — | 1.50 3.15 4.20 | — — — | V |
| Low - Level Input Voltage | V_{IL} | | 2.0 4.5 6.0 | — — — | — — — | — — — | 0.50 1.35 1.80 | — — — | V |
| High - Level Output Voltage | V_{OH} | $V_{IN} = V_{IH}$ or V_{IL} | $I_{OH} = -20\mu\text{A}$ | 2.0 4.5 6.0 | 1.9 4.4 5.9 | 2.0 4.5 6.0 | — — — | 1.9 4.4 5.9 | — — — |
| | | | $I_{OH} = -6\text{ mA}$ $I_{OH} = -7.8\text{ mA}$ | 4.5 6.0 | 4.18 5.68 | 4.31 5.80 | — — | 4.13 5.63 | — — |
| Low - Level Output Voltage | V_{OL} | $V_{IN} = V_{IH}$ or V_{IL} | $I_{OL} = 20\mu\text{A}$ | 2.0 4.5 6.0 | — — — | 0.0 0.0 0.0 | 0.1 0.1 0.1 | — — — | 0.1 0.1 0.1 |
| | | | $I_{OL} = 6\text{ mA}$ $I_{OL} = 7.8\text{ mA}$ | 4.5 6.0 | — — | 0.17 0.18 | 0.26 0.26 | — — | 0.33 0.33 |
| 3 - State Output Off - State Current | I_{OZ} | $V_{IN} = V_{IH}$ or V_{IL} $V_{OUT} = V_{CC}$ or GND | 6.0 | — | — | ± 0.5 | — | ± 5.0 | μA |
| Input Leakage Current | I_{IN} | $V_{IN} = V_{CC}$ or GND | 6.0 | — | — | ± 0.1 | — | ± 1.0 | |
| Quiescent Supply Current | I_{CC} | $V_{IN} = V_{CC}$ or GND | 6.0 | — | — | 4.0 | — | 40.0 | |

AC ELECTRICAL CHARACTERISTICS ($C_L = 50\text{pF}$, Input $t_r = t_f = 6\text{ns}$)

| PARAMETER | SYMBOL | TEST CONDITION | CL (pF) | V _{CC} (V) | Ta = 25°C | | | Ta = -40~85°C | | UNIT | |
|-------------------------------|-------------|-------------------------|------------|------------------------|-----------|------|------|---------------|------|------|--|
| | | | | | MIN. | TYP. | MAX. | MIN. | MAX. | | |
| Output Transition Time | t_{TLH} | | 50 | 2.0 | — | 25 | 60 | — | 75 | ns | |
| | t_{THL} | | | 4.5 | — | 7 | 12 | — | 15 | | |
| Propagation Delay Time | t_{pLH} | | | 6.0 | — | 6 | 10 | — | 13 | ns | |
| | t_{pHL} | | | 2.0 | — | 36 | 90 | — | 115 | | |
| | | | | 4.5 | — | 12 | 18 | — | 23 | | |
| | | | | 6.0 | — | 10 | 15 | — | 20 | | |
| | t_{pZL} | $R_L = 1\text{k}\Omega$ | 50 | 2.0 | — | 51 | 130 | — | 165 | pF | |
| | t_{pZH} | | | 4.5 | — | 17 | 26 | — | 33 | | |
| | | | | 6.0 | — | 14 | 22 | — | 28 | | |
| | t_{pLZ} | | 150 | 2.0 | — | 63 | 165 | — | 205 | | |
| | t_{pHZ} | | | 4.5 | — | 21 | 33 | — | 41 | | |
| | | | | 6.0 | — | 18 | 28 | — | 35 | | |
| Output Disable time | t_{pLZ} | $R_L = 1\text{k}\Omega$ | 50 | 2.0 | — | 32 | 125 | — | 155 | | |
| | t_{pHZ} | | | 4.5 | — | 15 | 25 | — | 31 | | |
| | | | | 6.0 | — | 14 | 21 | — | 26 | | |
| Input Capacitance | C_{IN} | | | | — | 5 | 10 | — | 10 | | |
| Output Capacitance | C_{OUT} | | | | — | 10 | — | — | — | | |
| Power Dissipation Capacitance | $C_{PD(1)}$ | TC74HC240A | | | — | 31 | — | — | — | pF | |
| | | TC74HC241A / 244A | | | — | 33 | — | — | — | | |

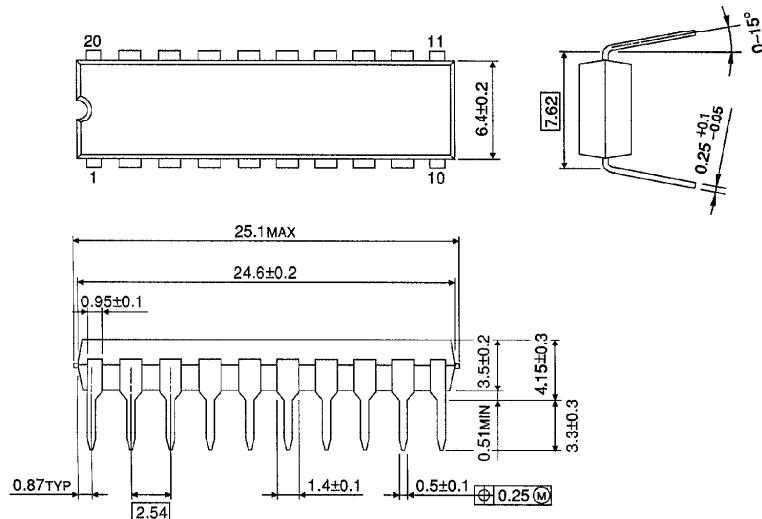
Note (1) C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation :

$$I_{CC(\text{opr})} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC} / 8 \text{ (per bit)}$$

DIP 20PIN OUTLINE DRAWING (DIP20-P-300-2.54A)

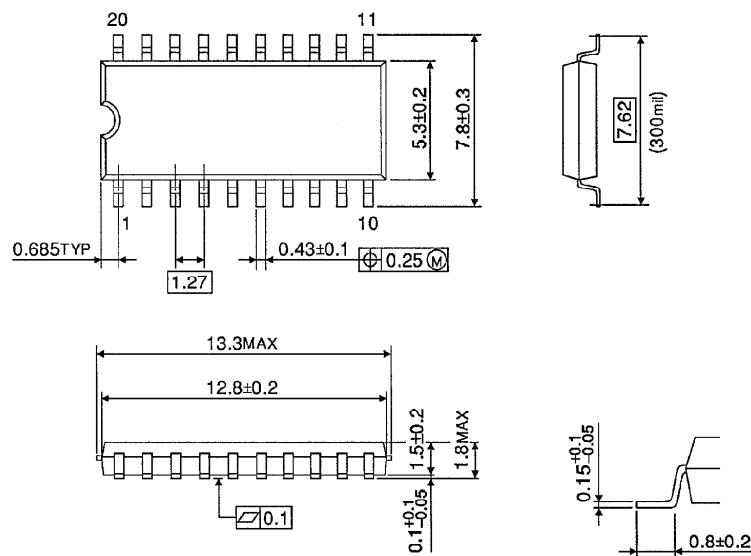
Unit in mm



Weight : 1.30g (Typ.)

SOP 20PIN (200mil BODY) OUTLINE DRAWING (SOP20-P-300-1.27)

Unit in mm

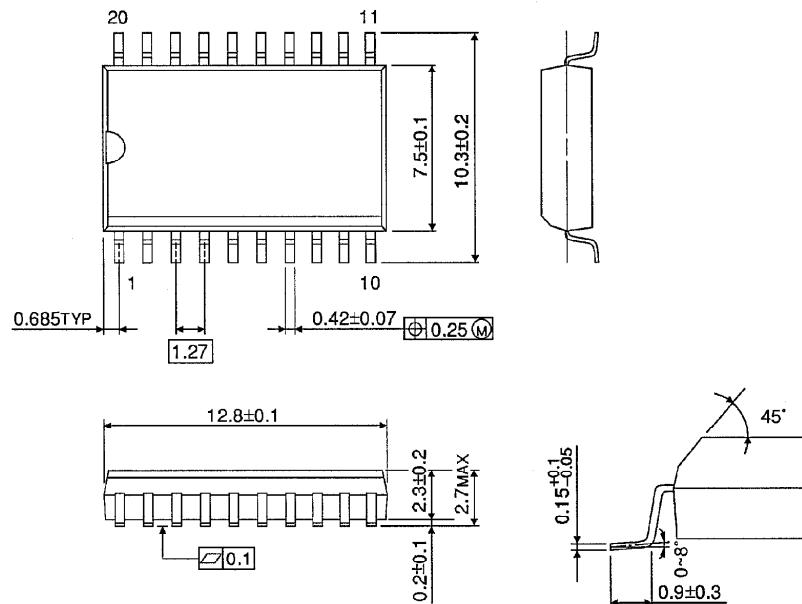


Weight : 0.22g (Typ.)

SOP 20PIN (300mil BODY) OUTLINE DRAWING (SOL20-P-300-1.27)

Unit in mm

(Note) This package is not available in Japan.



Weight : 0.46g (Typ.)